Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2005	capacitor and (dielectric with (aluminum adj oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/29 16:23
S2	581	S1 and (electrode with silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 13:31
S3	581	S2 and (dielectric with (hafnium adj oxide) or (tantalum adj oxide) or (titanium oxide) or (zirconium adj oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 13:34
S4	89	S3 and (second adj dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 13:33
S5	581	S2 and (dielectric with ((hafnium adj oxide) or (tantalum adj oxide) or (titanium oxide) or (zirconium adj oxide)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 13:34
S6	100	S5 and (dielectric with ((hafnium adj oxide) and (tantalum adj oxide) and (titanium oxide) and (zirconium adj oxide)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 13:36
S7	5	S6 and (third adj dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 13:37
S8	0	S7 and angstrom	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 13:37
S9	670	capacitor and (dielectric with (aluminum adj oxide)) and (silicon with electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/29 16:33
S10	101	S9 and ((lower adj electrode) with silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/29 17:29

S11	1867	257/532.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/29 17:29